# Medium-Power Complementary Silicon Transistors

 $\ldots$  for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain hFE = 4000 (Typ) @ IC = 5.0 Adc
- Monolithic Construction with Built-in Base-Emitter Shunt Resistors

# **MAXIMUM RATINGS**

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	VCEO	80	Vdc
Collector-Base Voltage	VCB	80	Vdc
Emitter–Base Voltage	VEB	5.0	Vdc
Collector Current	IC	10	Adc
Base Current	ΙΒ	0.2	Adc
Total Device Dissipation  @ T <sub>C</sub> = 25°C  Derate above 25°C	PD	150 0.857	Watts W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +200	°C

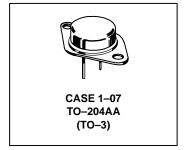
### THERMAL CHARACTERISTICS

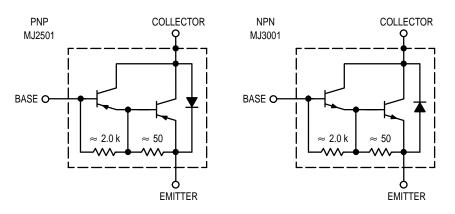
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$_{ heta}$ JC	1.17	°C/W

# PNP MJ2501 NPN MJ3001

Motorola Preferred Devices

10 AMPERE
DARLINGTON
POWER TRANSISTOR
COMPLEMENTARY
SILICON
80 VOLTS
150 WATTS





**Figure 1. Darlington Circuit Schematic** 

Preferred devices are Motorola recommended choices for future use and best overall value.



**ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector Emitter Breakdown Voltage <sup>(1)</sup> (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0)	V(BR)CEO	80	_	Vdc	
Collector–Emitter Leakage Current (VEB = 80 Vdc, RBE = 1.0 k ohm) (VEB = 80 Vdc, RBE = 1.0 k ohm, TC = 150°C)	ICER		1.0 5.0	mAdc	
Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	_	2.0	mAdc	
Collector Emitter Leakage Current (V <sub>CE</sub> = 40 Vdc, I <sub>B</sub> = 0)	ICEO	_	1.0	mAdc	
ON CHARACTERISTICS <sup>(1)</sup>			•		
DC Current Gain (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 3.0 Vdc)	hFE	1000	_	_	
Collector–Emitter Saturation Voltage ( $I_C = 5.0$ Adc, $I_B = 20$ mAdc) ( $I_C = 10$ Adc, $I_B = 50$ mAdc)	VCE(sat)	_	2.0 4.0	Vdc	
Base Emitter Voltage (IC = 5.0 Adc. $VCE = 3.0 \text{ Vdc}$ )	VRE(on)	_	3.0	Vdc	

<sup>(1)</sup> Pulse Test: Pulse Width  $\leq 300 \,\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

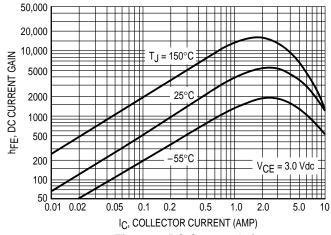


Figure 2. DC Current Gain

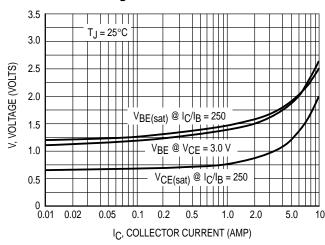


Figure 4. "On" Voltages

There are two limitations on the power handling ability of a transistor: junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; e.g., the transistor must not be subjected to greater dissipation

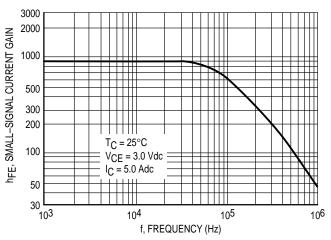


Figure 3. Small-Signal Current Gain

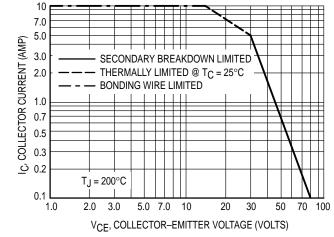
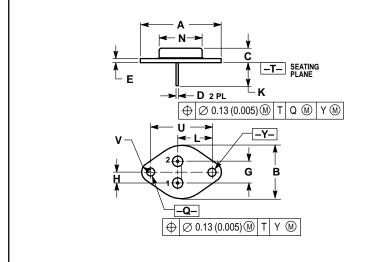


Figure 5. DC Safe Operating Area

than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

# **PACKAGE DIMENSIONS**



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	1.550 REF		39.37 REF		
В		1.050		26.67	
С	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
Е	0.055	0.070	1.40	1.77	
G	0.430	BSC	10.92	.92 BSC	
Η	0.215	BSC	5.46	46 BSC	
K	0.440	0.480	11.18	12.19	
L	0.665 BSC		16.89 BSC		
N		0.830		21.08	
ď	0.151	0.165	3.84	4.19	
5	1.187 BSC		30.15 BSC		
V	0.131	0.188	3 33	4 77	

STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR

**CASE 1-07** TO-204AA (TO-3) ISSUE Z

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